TPS7A16-Q1 60-V, 5-µA I_Q, 100-mA, Low-Dropout Voltage Regulator With Enable and Power-Good

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, T_A
  - Device HBM ESD classification level H2
  - Device CDM ESD classification level C3B
- Wide input voltage range: 3 V to 60 V
- Ultra-low quiescent current: 5 µA
- Quiescent current at shutdown: 1 µA
- Output current: 100 mA
- Low dropout voltage: 60 mV at 20 mA
- Accuracy: 2%
- Available in:
  - Fixed output voltage: 3.3 V, 5 V
  - Adjustable version from approximately 1.2 to 18.5 V
- Power-good with programmable delay
- Current-limit and thermal shutdown protections
- Stable with ceramic output capacitors: ≥ 2.2 µF
- Functional Safety-Capable
  - Document available to aid functional safety system design
- Package: High-thermal-performance, 8-pin HVSSOP thermal pad package

2 Applications

- Emergency call (eCall)
- Battery management systems (BMS)
- Onboard (OBC) and wireless chargers
- DC/DC converters

3 Description

The TPS7A16-Q1 ultra-low-power, low-dropout (LDO) voltage regulator offers the benefits of ultra-low quiescent current, high input voltage, and miniaturized, high-thermal-performance packaging.

The TPS7A16-Q1 is designed for continuous or sporadic (power backup) battery-powered applications where ultra-low quiescent current is critical to extending system battery life.

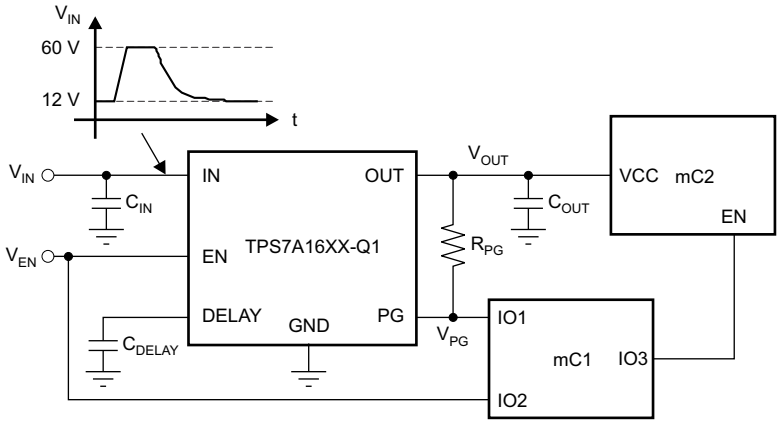
The TPS7A16-Q1 offers an enable pin (EN) compatible with standard CMOS logic and an integrated open-drain, active-high, power-good output (PG) with a user-programmable delay. These pins are intended for use in microcontroller-based, battery-powered applications where power-rail sequencing is required.

In addition, the TPS7A16-Q1 is designed for generating a low-voltage supply from multicell solutions ranging from high-cell-count, power-tool packs to automotive applications; not only can this device supply a well-regulated voltage rail, but the TPS7A16-Q1 can also withstand and maintain regulation during voltage transients. These features translate to simpler and more cost-effective, electrical surge-protection circuitry.

Package Information

PART NUMBER	PACKAGE(1)	BODY SIZE (NOM)
TPS7A16-Q1	DGN (HVSSOP, 8)	3.00 mm × 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Typical Application Schematic

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

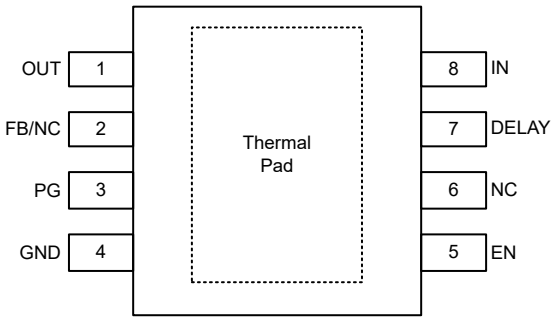
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (August 2014) to Revision E (May 2023)	Page
• Added *Functional Safety* and *Package* bullets to *Features* section	1
• Added links to *Applications* section	1
• Changed pinout drawing to show pin 2 as FB/NC instead of FB/DNC and changed description of pin 2 in *Pin Functions* table	3

Changes from Revision C (August 2014) to Revision D (May 2016)	Page
• Changed data sheet title	1
• Changed *Handling Ratings* table to *ESD Ratings*; moved storage temperature to *Absolute Maximum Ratings*	4
• Changed maximum EN pin voltage and added a row for EN slew rate	5
• Changed UNIT for accuracy on V_{OUT}	6
• Changed *Ground current* to *Quiescent current*	6
• Changed Figure 6-2	7
• Changed caption of Figure 6-3	7
• Changed and added text in *Enable (EN)* section	10
• Moved three paragraphs of text from *Layout Examples* to *Layout Guidelines*	18

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5 Pin Configuration and Functions



NC – No internal connection

Figure 5-1. DGN Package, 8-Pin HVSSOP With Exposed Thermal Pad (Top View)

Table 5-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
DELAY	7	O	Delay pin. Connect a capacitor to GND to adjust the PG delay time; leave open if the reset function is not needed.
EN	5	I	Enable pin. This pin turns the regulator on or off. If $V_{EN} \geq V_{EN_HI}$, the regulator is enabled. If $V_{EN} \leq V_{EN_LO}$, the regulator is disabled. If not used, the EN pin can be connected to IN. Make sure that $V_{EN} \leq V_{IN}$ at all times.
FB/NC	2	I	This pin is a feedback pin when using an external resistor divider or an NC pin when using the device with a fixed output voltage. When using the adjustable device, this pin must be connected through a resistor divider to the output for the device to function. If using a fixed output this pin can either be left floating or connected to GND.
GND	4	—	Ground pin
IN	8	I	Regulator input supply pin. A capacitor > 0.1 µF must be tied from this pin to ground to assure stability. Connect a 10-µF ceramic capacitor from IN to GND (as close to the device as possible) to reduce circuit sensitivity to printed-circuit-board (PCB) layout, especially when long input tracer or high source impedances are encountered.
NC	6	—	This pin can be left open or tied to any voltage between GND and IN.
OUT	1	O	Regulator output pin. A capacitor > 2.2 µF must be tied from this pin to ground to assure stability. Connect a 10-µF ceramic capacitor from OUT to GND (as close to the device as possible) to maximize ac performance.
PG	3	O	Power-good pin. Open-collector output; leave open or connect to GND if the power-good function is not needed.
Thermal pad		—	Solder to printed circuit board (PCB) to enhance thermal performance. Although the thermal pad can be left floating, connecting the thermal pad to the GND plane is highly recommended.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Voltage	IN pin to GND pin	–0.3	62	V
	OUT pin to GND pin	–0.3	20	
	OUT pin to IN pin	–62	0.3	
	FB pin to GND pin	–0.3	3	
	FB pin to IN pin	–62	0.3	
	EN pin to IN pin	–62	0.3	
	EN pin to GND pin	–0.3	62	
	PG pin to GND pin	–0.3	5.5	
	DELAY pin to GND pin	–0.3	5.5	
Current	Peak output	Internally limited		
Temperature	Operating virtual junction, T_J, absolute maximum range(2)	–40	150	°C
	Storage temperature range	–65	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Permanent damage does not occur to the part operating within this range, though electrical performance is not guaranteed outside the operating ambient temperature range.

6.2 ESD Ratings

				MIN	MAX	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002(1)		–2	2	kV
		Charged device model (CDM), per AEC Q100-011	Corner pins (OUT, GND, IN, and EN)	–750	750	V
			Other pins	–500	500	

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

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6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Unregulated input	3		60	V
V_{OUT}	Regulated output	1.2		18	V
EN	Voltage	0		V_{IN}	V
	Slew rate, voltage ramp-up			1.5	V/µs
DELAY	Delay pin voltage	0		5	V
PG	Power-good pin voltage	0		5	V
T_J	Operating junction temperature range	–40		150	°C

6.4 Thermal Information

THERMAL METRIC[1]		TPS7A16-Q1 DGN (HVSSOP) 8 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	66.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	45.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	34.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	1.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	34.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance	14.9	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application note.

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6.5 Electrical Characteristics

at T_A= –40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 µA, C_{IN} = 1 µF, C_{OUT} = 2.2 µF, and FB tied to OUT (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range		3		60	V
V_{REF}	Internal reference	T_A = 25°C, V_{FB} = V_{REF}, V_{IN} = 3 V, I_{OUT} = 10 µA	1.169	1.193	1.217	V
V_{UVLO}	Undervoltage lockout threshold			2.7		V
V_{OUT}	Output voltage range	V_{IN} ≥ $V_{OUT(NOM)}$ + 0.5 V	V_{REF}		18.5	V
	Nominal accuracy	T_A = 25°C, V_{IN} = 3 V, I_{OUT} = 10 µA	–2%		2%	
	Overall accuracy	$V_{OUT(NOM)}$ + 0.5 V ≤ V_{IN} ≤ 60 V(1) 10 µA ≤ I_{OUT} ≤ 100 mA	–2%		2%	
$\Delta V_{O(\Delta VI)}$	Line regulation	3 V ≤ V_{IN} ≤ 60 V		±1		$\%V_{OUT}$
$\Delta V_{O(\Delta IO)}$	Load regulation	10 µA ≤ I_{OUT} ≤ 100 mA		±1		$\%V_{OUT}$
V_{DO}	Dropout voltage	V_{IN} = 4.5 V, $V_{OUT(NOM)}$ = 5 V, I_{OUT} = 20 mA		60		mV
		V_{IN} = 4.5 V, $V_{OUT(NOM)}$ = 5 V, I_{OUT} = 100 mA		265	500	mV
I_{LIM}	Current limit	V_{OUT} = 90% $V_{OUT(NOM)}$, V_{IN} = 3.0 V	101	225	400	mA
I_Q	Quiescent current	3 V ≤ V_{IN} ≤ 60 V, I_{OUT} = 10 µA		5	15	µA
		I_{OUT} = 100 mA		5		µA
I_{SHDN}	Shutdown supply current	V_{EN} = 0.4 V		0.59	5.0	µA
I_{FB}	Feedback current(2)		–1	0.0	1	µA
I_{EN}	Enable current	3 V ≤ V_{IN} ≤ 12 V, V_{IN} = V_{EN}	–1	0.01	1	µA
V_{EN_HI}	Enable high-level voltage		1.2			V
V_{EN_LO}	Enable low- level voltage				0.3	V
V_{IT}	PG trip threshold	OUT pin floating, V_{FB} increasing, V_{IN} ≥ V_{IN_MIN}	85		95	$\%V_{OUT}$
		OUT pin floating, V_{FB} decreasing, V_{IN} ≥ V_{IN_MIN}	83		93	$\%V_{OUT}$
V_{HYS}	PG trip hysteresis			2.3	4	$\%V_{OUT}$
$V_{PG, LO}$	PG output low voltage	OUT pin floating, V_{FB} = 80% V_{REF}, I_{PG}= 1mA			0.4	V
$I_{PG, LKG}$	PG leakage current	V_{PG}= $V_{OUT(NOM)}$	–1		1	µA
I_{DELAY}	DELAY pin current			1	2	µA
PSRR	Power-supply rejection ratio	V_{IN} = 3 V, $V_{OUT(NOM)}$ = V_{REF}, C_{OUT} = 10 µF, f = 100 Hz		50		dB
T_{SD}	Thermal shutdown temperature	Shutdown, temperature increasing		170		°C
		Reset, temperature decreasing		150		°C
T_A	Operating ambient temperature range		–40		125	°C

(1) Maximum input voltage is limited to 24 V because of the package power dissipation limitations at full load (P ≈ (V_{IN} – V_{OUT}) × I_{OUT} = (24 V – V_{REF}) × 50 mA ≈ 1.14 W). The device is capable of sourcing a maximum current of 50 mA at higher input voltages as long as the power dissipated is within the thermal limits of the package plus any external heat sinking.

(2) I_{FB} > 0 flows out of the device.

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6.6 Typical Characteristics

at T_A = –40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 µA, C_{IN} = 1 µF, C_{OUT} = 2.2 µF, and FB tied to OUT (unless otherwise noted)

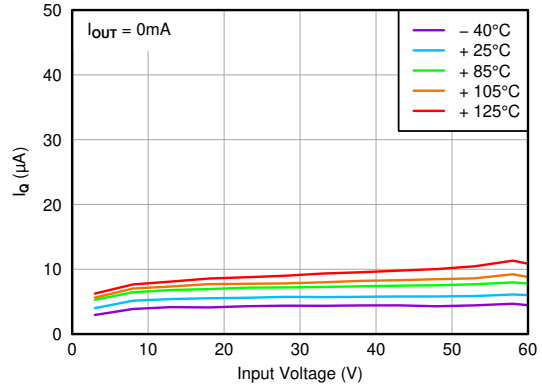


Figure 6-1. Quiescent Current vs Input Voltage

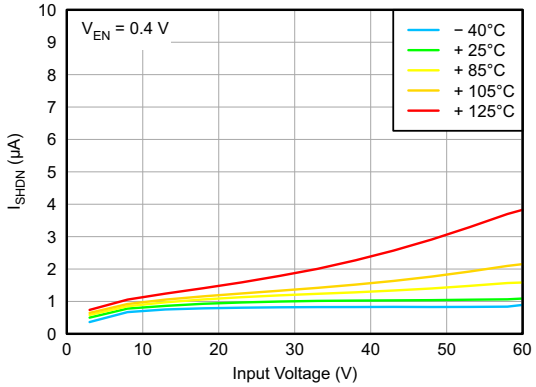


Figure 6-2. Shutdown Current vs Input Voltage

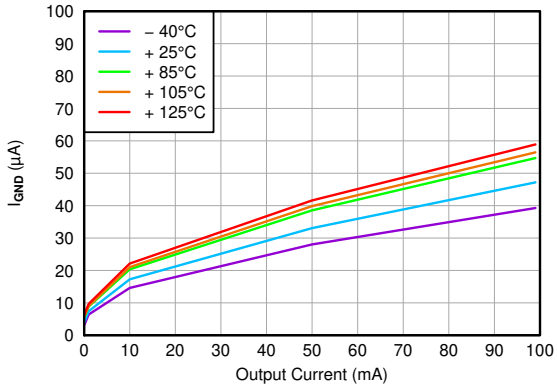


Figure 6-3. Quiescent Current vs Output Current

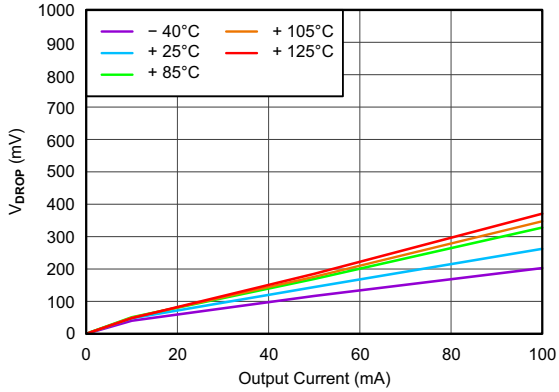


Figure 6-4. Dropout Voltage vs Output Current

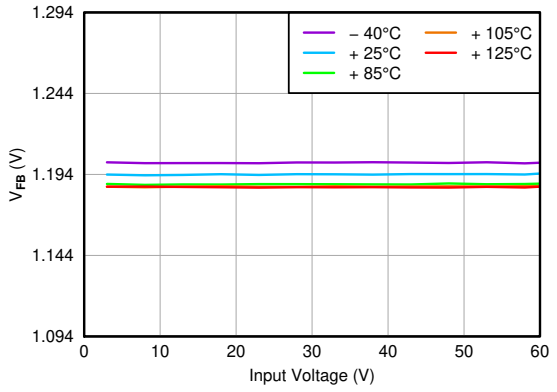


Figure 6-5. Feedback Voltage vs Input Voltage

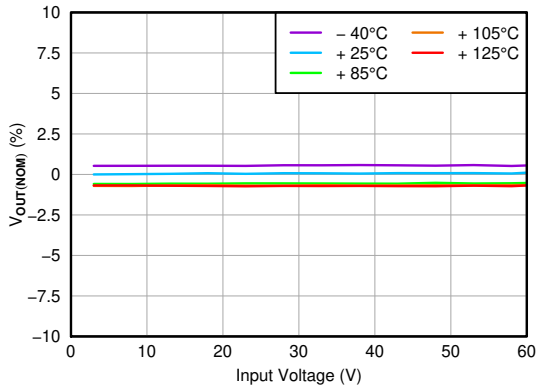


Figure 6-6. Line Regulation

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6.6 Typical Characteristics (continued)

at T_A = –40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 µA, C_{IN} = 1 µF, C_{OUT} = 2.2 µF, and FB tied to OUT (unless otherwise noted)

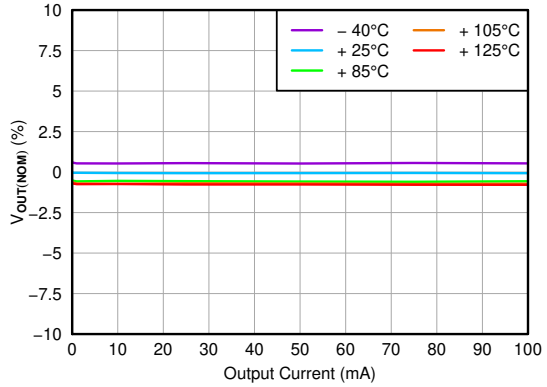


Figure 6-7. Load Regulation

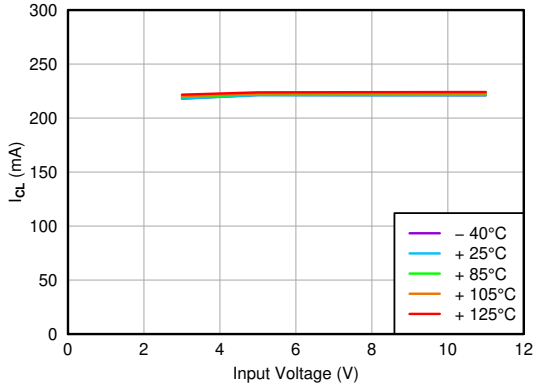


Figure 6-8. Current Limit vs Input Voltage

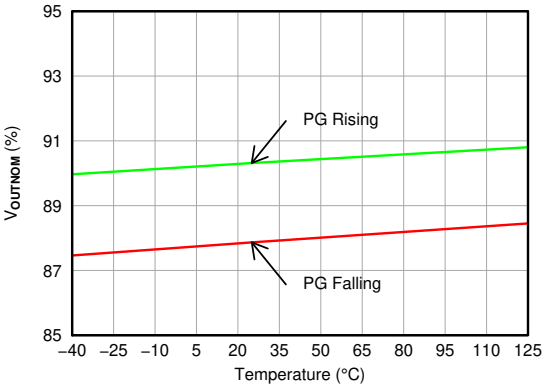


Figure 6-9. Power-Good Threshold Voltage vs Temperature

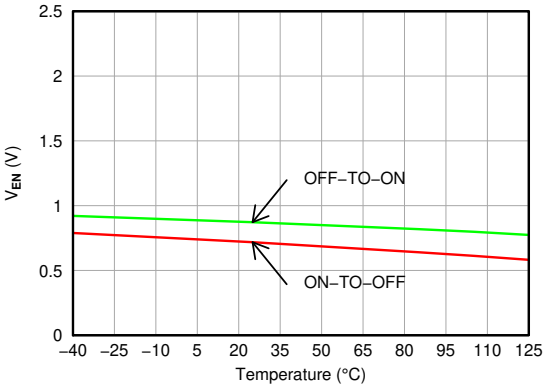


Figure 6-10. Enable Threshold Voltage vs Temperature

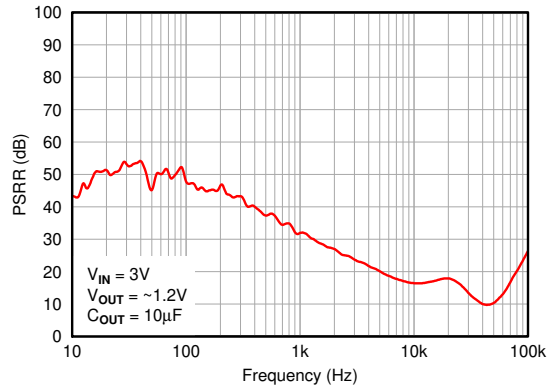


Figure 6-11. Power-Supply Rejection Ratio

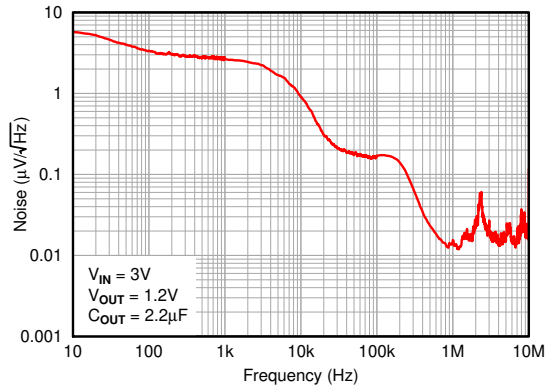


Figure 6-12. Output Spectral Noise Density

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6.6 Typical Characteristics (continued)

at T_A = –40°C to +125°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or V_{IN} = 3 V (whichever is greater), V_{EN} = V_{IN}, I_{OUT} = 10 µA, C_{IN} = 1 µF, C_{OUT} = 2.2 µF, and FB tied to OUT (unless otherwise noted)

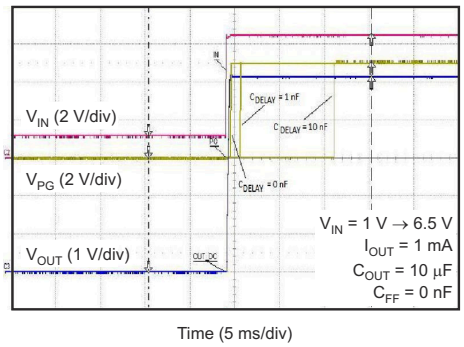


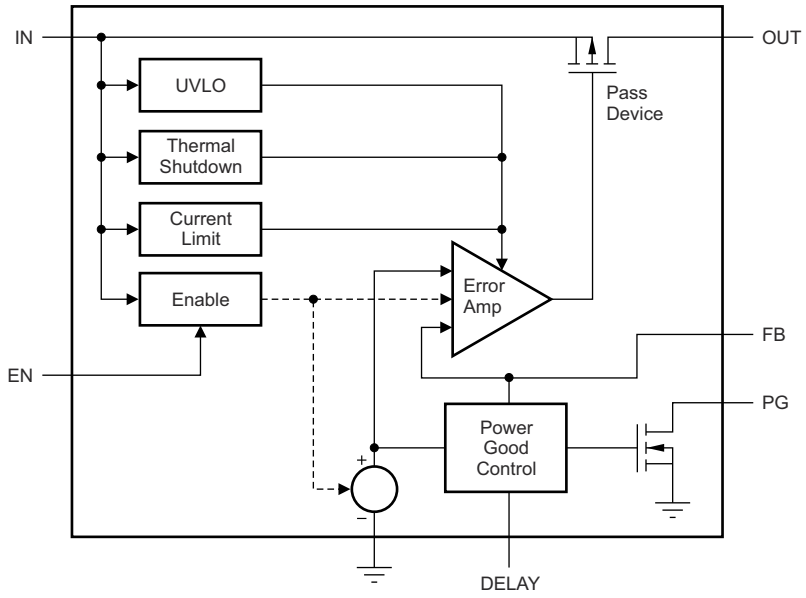
Figure 6-13. Power-Good Delay

7 Detailed Description

7.1 Overview

The TPS7A16-Q1 is an ultra low power, low-dropout (LDO) voltage regulator that offers the benefits of ultra-low quiescent current, high input voltage, and miniaturized, high thermal-performance packaging. The TPS7A16-Q1 also offers an enable pin (EN) and integrated open-drain, active-high, power-good output (PG) with a user-programmable delay.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Enable (EN)

The enable pin is a high-voltage-tolerant pin. A high input on EN actives the device and turns on the regulator. For self-bias applications, connect this input to the V_{IN} pin. Make sure that $V_{EN} \leq V_{IN}$ at all times.

When the enable signal is PWM pulses, the slew rate of the rising and falling edges must be less than 1.5 V/µs. Adding a 0.1-µF capacitor from the EN pin to GND is recommended.

7.3.2 Regulated Output (V_{OUT})

The V_{OUT} pin is the regulated output based on the required voltage. The output has current limitation. During initial power-up, the regulator has a soft-start incorporated to control the initial current through the pass transistor. In the event that the regulator drops out of regulation, the output tracks the input minus a drop based on the load current. When the input voltage drops below the undervoltage lockout (UVLO) threshold, the regulator shuts down until the input voltage recovers above the minimum start-up level.

7.3.3 PG Delay Timer (DELAY)

The power-good delay time (t_{DELAY}) is defined as the time period from when V_{OUT} exceeds the PG trip threshold voltage (V_{IT}) to when the PG output is high. This power-good delay time is set by an external capacitor (C_{DELAY}) connected from the DELAY pin to GND; this capacitor is charged from 0 V to approximately 1.8 V by the DELAY pin current (I_{DELAY}) when V_{OUT} exceeds the PG trip threshold (V_{IT}).

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7.4 Device Functional Modes

7.4.1 Power-Good

The power-good (PG) pin is an open-drain output and can be connected to any 5.5-V or lower rail through an external pullup resistor. When no C_{DELAY} is used, the PG output is high-impedance when V_{OUT} is greater than the PG trip threshold (V_{IT}). If V_{OUT} drops below V_{IT}, the open-drain output turns on and pulls the PG output low. If output voltage monitoring is not needed, the PG pin can be left floating or connected to GND.

To provide proper operation of the power-good feature, maintain $V_{IN} \geq 3$ V (V_{IN_MIN}).

7.4.2 Power-Good Delay and Delay Capacitor

The power-good delay time (t_{DELAY}) is defined as the time period from when V_{OUT} exceeds the PG trip threshold voltage (V_{IT}) to when the PG output is high. This power-good delay time is set by an external capacitor (C_{DELAY}) connected from the DELAY pin to GND; this capacitor is charged from 0 V to approximately 1.8 V by the DELAY pin current (I_{DELAY}) when V_{OUT} exceeds the PG trip threshold (V_{IT}).

When C_{DELAY} is used, the PG output is high-impedance when V_{OUT} exceeds V_{IT}, and V_{DELAY} exceeds V_{REF}.

The power-good delay time can be calculated using: $t_{DELAY} = (C_{DELAY} \times V_{REF}) / I_{DELAY}$. For example, when C_{DELAY} = 10 nF, the PG delay time is approximately 12 ms; that is, (10 nF × 1.193 V) / 1 µA = 11.93 ms.

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TPS7A16-Q1 ultra-low-power voltage regulator offers the benefit of ultra-low quiescent current, high input voltage, and miniaturized, high-thermal-performance packaging.

The TPS7A16-Q1 is designed for continuous or sporadic (power backup) battery-operated applications where ultra-low quiescent current is critical to extending system battery life.

8.2 Typical Applications

8.2.1 TPS7A1601-Q1 Circuit as an Adjustable Regulator

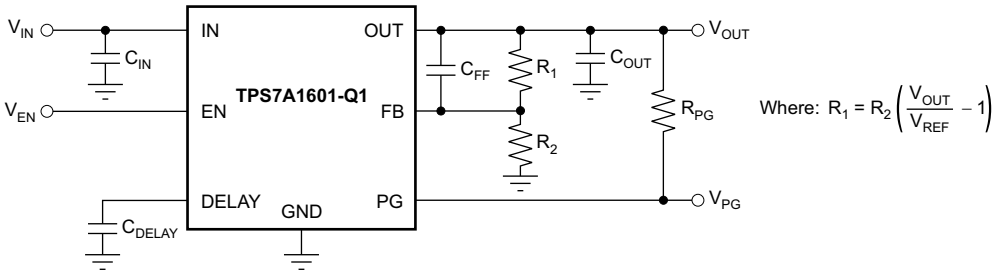


Figure 8-1. TPS7A1601-Q1 Circuit as an Adjustable Regulator Schematic

8.2.1.1 Design Requirements

Table 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 40 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

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8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Adjustable Voltage Operation

The TPS7A1601-Q1 has an output voltage range from 1.194 V to 20 V. The nominal output of the device is set by two external resistors, as shown in Figure 8-2:

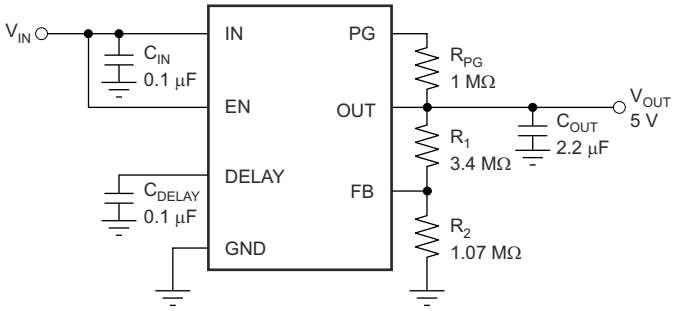


Figure 8-2. Adjustable Operation

R_1 and R_2 can be calculated for any output voltage range using the formula shown in Equation 1:

$$R_1 = R_2 \left(\frac{V_{OUT}}{V_{REF}} - 1 \right) \quad (1)$$

8.2.1.2.2 Resistor Selection

Use resistors in the order of megaohms (MΩ) to keep the overall quiescent current of the system as low as possible (by making the current used by the resistor divider negligible compared to the quiescent current of the device).

If greater voltage accuracy is required, take into account the voltage offset contributions as a result of feedback current and use 0.1% tolerance resistors.

Table 8-2 shows the resistor combination to achieve an output for a few of the most common rails using commercially available 0.1% tolerance resistors to maximize nominal voltage accuracy, while adhering to the formula shown in Equation 1.

Table 8-2. Selected Resistor Combinations

V_{OUT}	R_1	R_2	$V_{OUT}/(R_1 + R_2) \ll I_Q$	NOMINAL ACCURACY
1.194 V	0 Ω	∞	0 µA	±2%
1.8 V	1.18 MΩ	2.32 MΩ	514 nA	±(2% + 0.14%)
2..5 V	1.5 MΩ	1.37 MΩ	871 nA	±(2% + 0.16%)
3.3 V	2 MΩ	1.13 MΩ	1056 nA	±(2% + 0.35%)
5 V	3.4 MΩ	1.07 MΩ	1115 nA	±(2% + 0.39%)
10 V	7.87 MΩ	1.07 MΩ	1115 nA	±(2% + 0.42%)
12 V	14.3 MΩ	1.58 MΩ	755 nA	±(2% + 0.18%)
15 V	42.2 MΩ	3.65 MΩ	327 nA	±(2% + 0.19%)
18 V	16.2 MΩ	1.15 MΩ	1038 nA	±(2% + 0.26%)

Close attention must be paid to board contamination when using high-value resistors; board contaminants can significantly impact voltage accuracy. If board cleaning measures cannot be ensured, consider using a fixed-voltage version of the TPS7A16 or using resistors in the order of hundreds or tens of kiloohms (kΩ).

8.2.1.2.3 Capacitor Recommendations

Use low equivalent-series-resistance (ESR) capacitors for the input, output, and feed-forward capacitors. Ceramic capacitors with X7R and X5R dielectrics are preferred. These dielectrics offer more stable

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characteristics. Ceramic X7R capacitors offer improved overtemperature performance, whereas ceramic X5R capacitors are the most cost-effective and are available in higher values.

However, high-ESR capacitors can degrade PSRR.

8.2.1.2.4 Input and Output Capacitor Requirements

The TPS7A16-Q1 ultra-low-power, high-voltage linear regulators achieve stability with a minimum input capacitance of 0.1 µF and output capacitance of 2.2 µF; however, use a 10-µF ceramic capacitor to maximize ac performance.

8.2.1.2.5 Feed-Forward Capacitor (Only for Adjustable Version)

Although a feed-forward capacitor (C_{FF}) from OUT to FB is not needed to achieve stability, using a 0.01-µF feed-forward capacitor to maximizes ac performance.

8.2.1.2.6 Transient Response

As with any regulator, increasing the size of the output capacitor reduces over- and undershoot magnitude but increases the duration of the transient response.

8.2.1.3 Application Curves

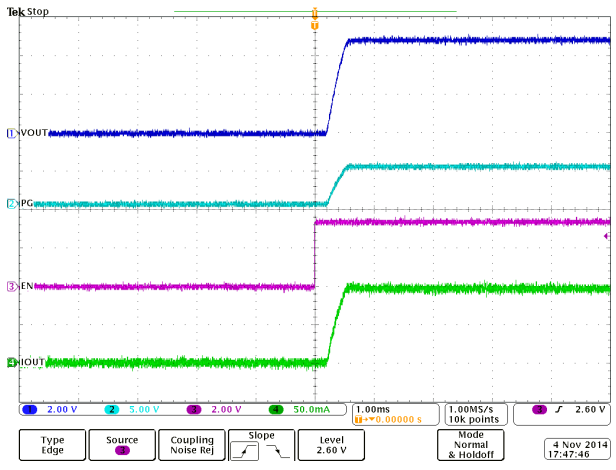


Figure 8-3. CH1 is VOUT, CH2 is PG, CH4 is Iout, VIN is 12 V and Ready Before EN

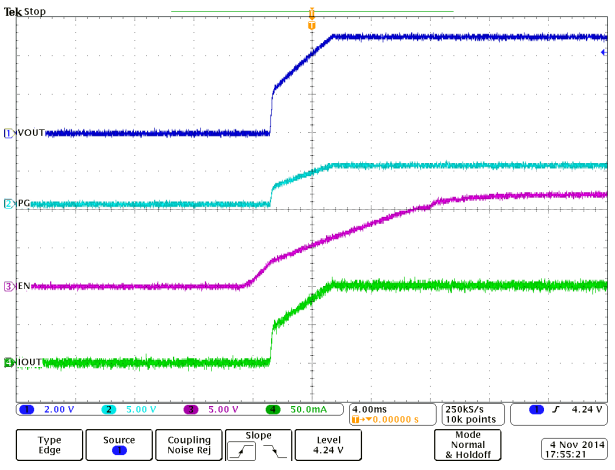


Figure 8-4. CH1 is VOUT, CH2 is PG, CH3 is EN, CH4 is Iout, VIN is 12 V Connected to EN

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8.2.2 Automotive Applications

The TPS7A16-Q1 maximum input voltage of 60 V makes the device designed for use in automotive applications where high-voltage transients are present.

Events such as load-dump overvoltage (where the battery is disconnected while the alternator is providing current to a load) can cause voltage spikes from 25 V to 60 V. To prevent any damage to sensitive circuitry, local transient voltage suppressors can be used to cap voltage spikes to lower, more manageable voltages.

The TPS7A16-Q1 can be used to simplify and lower costs in such cases. The very high voltage range allows this regulator not only to withstand the voltages coming out of these local transient voltage suppressors, but even replace them, thus lowering system cost and complexity.

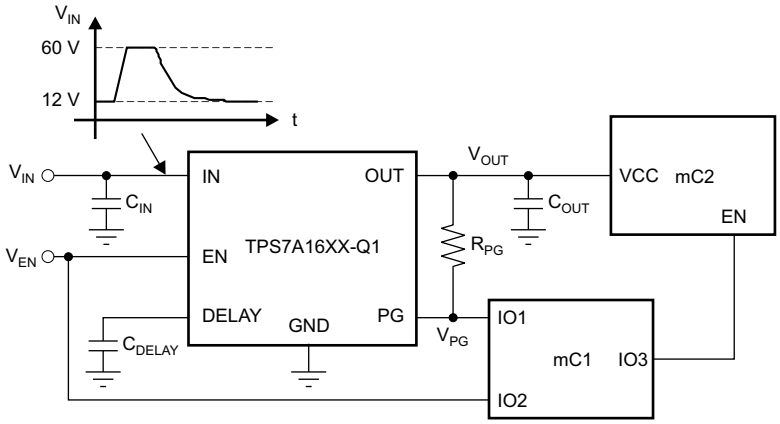


Figure 8-5. Low-Power Microcontroller Rail Sequencing in Automotive Applications Subjected to Load-Dump Transients

8.2.2.1 Design Requirements

Table 8-3. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 60 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

8.2.2.2 Detailed Design Procedure

See the *Capacitor Recommendations* and *Input and Output Capacitor Requirements* sections.

8.2.2.2.1 Device Recommendations

The output is fixed, so choose the TPS7A1650-Q1.

8.2.2.3 Application Curves

See Figure 8-3 and Figure 8-4.

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8.2.3 Multicell Battery Packs

Currently, battery packs can employ up to a dozen cells in series that, when fully charged, can have voltages of up to 55 V. Internal circuitry in these battery packs is used to prevent overcurrent and overvoltage conditions that can degrade battery life or even pose a safety risk; this internal circuitry is often managed by a low-power microcontroller, such as TI's MSP430™. See the overview for microcontrollers (MCU) for more information.

The microcontroller continuously monitors the battery, whether the battery is in use or not. Although this microcontroller can be powered by an intermediate voltage taken from the multicell array, this approach unbalances the battery pack, degrading the battery life or adding cost to implement more complex cell-balancing topologies.

The best approach to power this microcontroller is to regulate down the voltage from the entire array to discharge every cell equally and prevent any balancing issues. This approach reduces system complexity and cost.

The TPS7A16-Q1 can be used for this application because this device can handle very high voltages (from the entire multicell array) and has very low quiescent current (to maximize battery life).

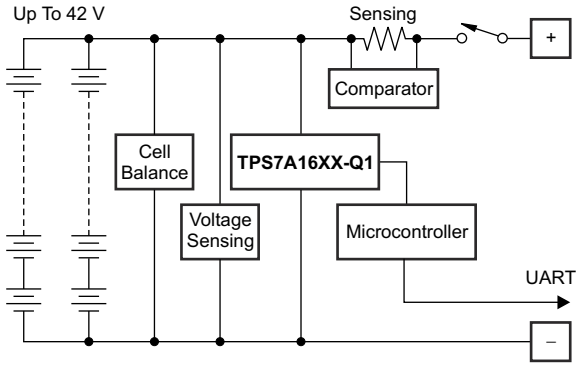


Figure 8-6. Protection Based on Low-Power Microcontroller Power From Multicell Battery Packs

8.2.3.1 Design Requirements

Table 8-4. Device Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 55 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

8.2.3.2 Detailed Design Procedure

See the *Device Recommendations*, *Capacitor Recommendations*, and *Input and Output Capacitor Requirements* sections.

8.2.3.3 Application Curves

See Figure 8-3 and Figure 8-4.

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8.2.4 Battery-Operated Power Tools

High-voltage multicell battery packs support high-power applications (such as power tools) with high current drain when in use, highly intermittent use cycles, and physical separation between battery and motor.

In these applications, a microcontroller or microprocessor controls the motor. This microcontroller must be powered with a low-voltage rail coming from the high-voltage, multicell battery pack; as mentioned previously, powering this microcontroller or microprocessor from an intermediate voltage from the multicell array causes battery-pack life degradation or added system complexity because of cell balancing issues. In addition, this microcontroller or microprocessor must be protected from the high-voltage transients because of the motor inductance.

The TPS7A16-Q1 can be used to power the motor-controlled microcontroller or microprocessor; the device low quiescent current maximizes battery shelf life, and very high-voltage capabilities simplify system complexity by replacing voltage suppression filters, thus lowering system cost.

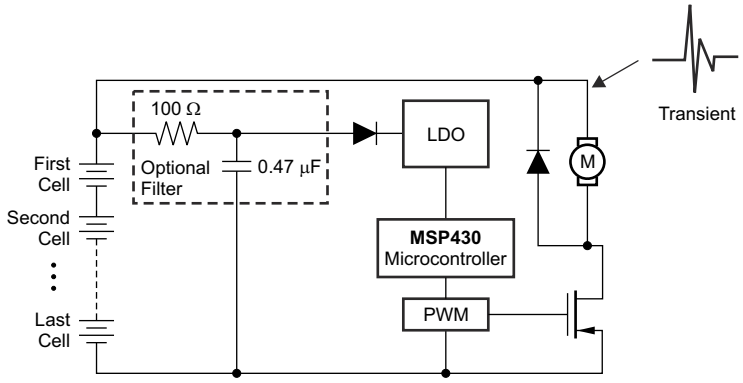


Figure 8-7. Low Power Microcontroller Power From Multicell Battery Packs in Power Tools

8.2.4.1 Design Requirements

Table 8-5. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	5.5 V to 60 V
Output voltage	5 V
Output current rating	100 mA
Output capacitor range	2.2 µF to 100 µF
Delay capacitor range	100 pF to 100 nF

8.2.4.2 Detailed Design Procedure

See the *Device Recommendations*, *Capacitor Recommendations*, and *Input and Output Capacitor Requirements* sections.

8.2.4.3 Application Curves

See Figure 8-3 and Figure 8-4.

8.3 Power Supply Recommendations

Design of the device is for operation from an input voltage supply with a range between 3 V and 60 V. This input supply must be well regulated. The TPS7A16-Q1 ultra-low-power, high-voltage linear regulator achieves stability with a minimum input capacitance of 0.1 µF and output capacitance of 2.2 µF; however, the use of a 10-µF ceramic capacitor to maximize ac performance is highly recommended.

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8.4 Layout

8.4.1 Layout Guidelines

To improve ac performance such as PSRR, output noise, and transient response, design the board with separate ground planes for IN and OUT, with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor must connect directly to the GND pin of the device.

Equivalent series inductance (ESL) and ESR must be minimized in order to maximize performance and provide stability. Every capacitor must be placed as close as possible to the device and on the same side of the PCB as the regulator.

Do not place any of the capacitors on the opposite side of the PCB from where the regulator is installed. Using vias and long traces is strongly discouraged because these components can impact system performance negatively and even cause instability.

If possible, and to provide the maximum performance denoted in this product data sheet, use the same layout pattern used for the TPS7A16-Q1 evaluation board, available at www.ti.com.

Layout is a critical part of good power-supply design. There are several signal paths that conduct fast-changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power-supply performance. To help eliminate these problems, bypass the IN pin to ground with a low-ESR ceramic bypass capacitor with X5R or X7R dielectric.

Acceptable performance can possibly be obtained with alternative PCB layouts; however, the layout and schematic herein have been shown to produce good results and are meant as a guideline.

Figure 8-8 shows the schematic for the suggested layout. Figure 8-9 and Figure 8-10 show the top and bottom printed circuit board (PCB) layers for the suggested layout.

8.4.1.1 Additional Layout Considerations

The high impedance of the FB pin makes the regulator sensitive to parasitic capacitances that can couple undesirable signals from nearby components (especially from logic and digital devices, such as microcontrollers and microprocessors); these capacitively-coupled signals can produce undesirable output voltage transients. In these cases, use a fixed-voltage version of the TPS7A16-Q1, or isolate the FB node by flooding the local PCB area with ground-plane copper to minimize any undesirable signal coupling.

8.4.1.2 Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Using heavier copper increases the effectiveness of removing heat from the device. The addition of plated through-holes to heat dissipating layers also improves the heat sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass element, as shown in Equation 2:

$$P_D = (V_{IN} - V_{OUT})\ I_{OUT} \quad (2)$$

8.4.1.3 Thermal Considerations

Thermal protection disables the output when the junction temperature rises to approximately 170°C, allowing the device to cool. When the junction temperature cools to approximately 150°C, the output circuitry is enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit can cycle on and off. This cycling limits the dissipation of the regulator, protecting the regulator from damage as a result of overheating.

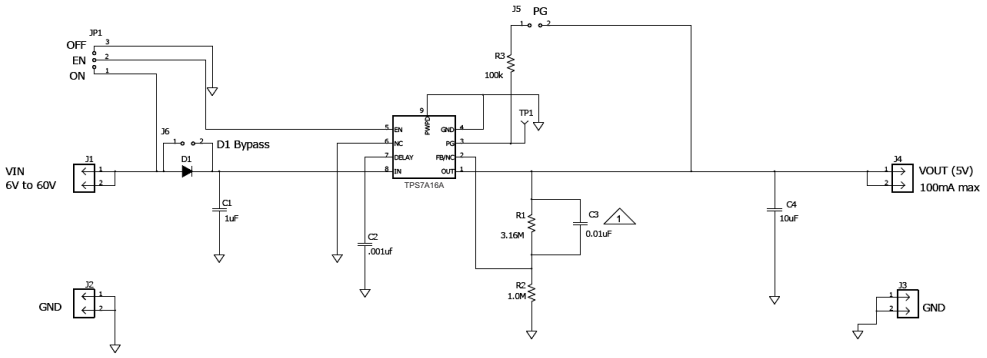
Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heat-spreading area. For reliable operation, limit junction temperature to a maximum of 125°C at the worst-case ambient temperature for a given application. To estimate the margin of safety in a complete design (including the copper heat-spreading area), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection must trigger at least 45°C above

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the maximum expected ambient condition of the particular application. This configuration produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS7A16-Q1 is designed to protect against overload conditions. This circuitry is not intended to replace proper heat sinking. Continuously running the TPS7A16-Q1 into thermal shutdown degrades device reliability.

8.4.2 Layout Examples



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Figure 8-8. Schematic for Suggested Layout

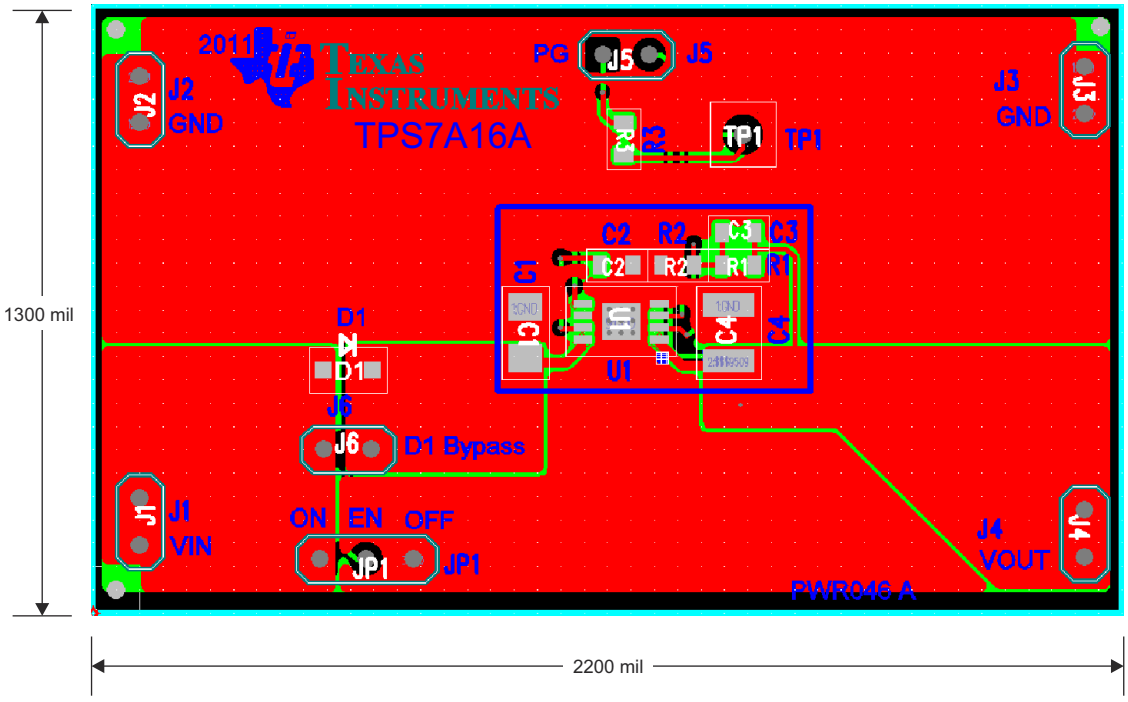


Figure 8-9. Suggested Layout: Top Layer

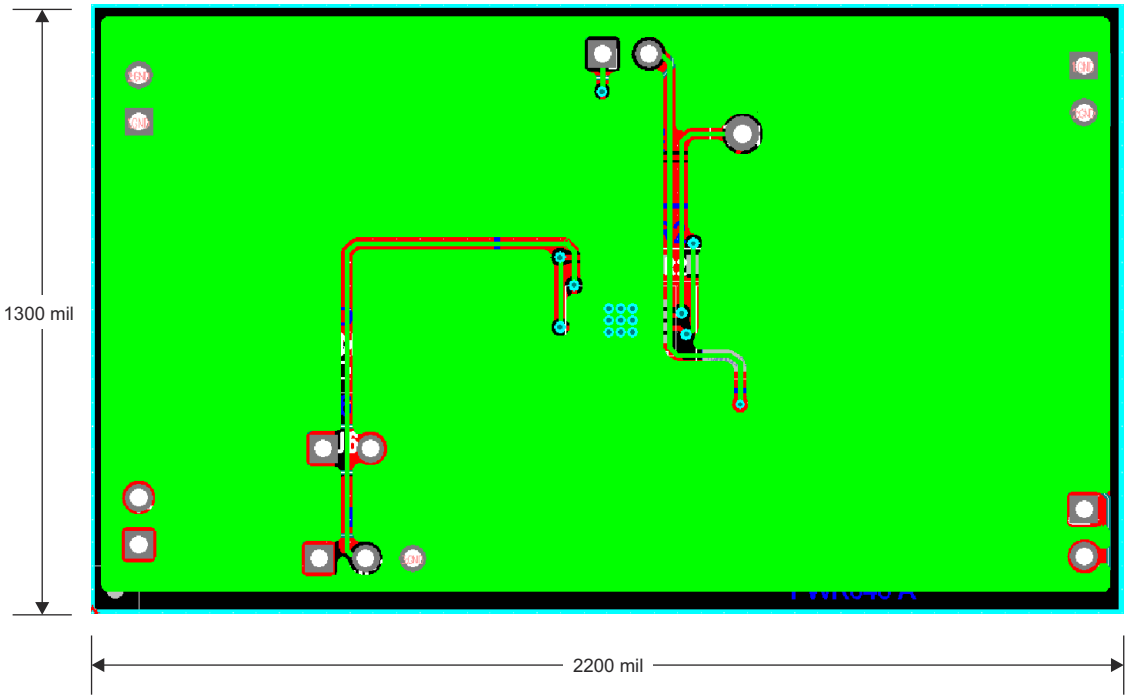


Figure 8-10. Suggested Layout: Bottom Layer

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9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS7A1601QDGNRQ1	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PXZQ
TPS7A1601QDGNRQ1.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PXZQ
TPS7A1633QDGNRQ1	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PXYQ
TPS7A1633QDGNRQ1.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PXYQ
TPS7A1650QDGNRQ1	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PYAQ
TPS7A1650QDGNRQ1.A	Active	Production	HVSSOP (DGN) | 8	2500 | LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	PYAQ

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS7A16-Q1 :

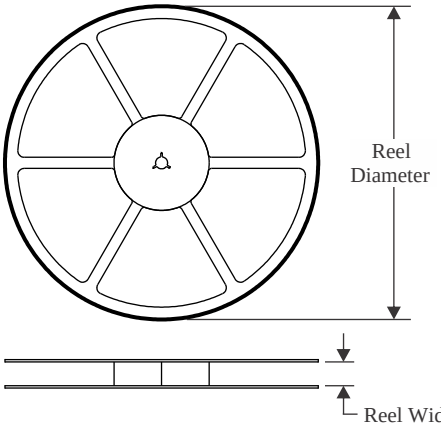
- Catalog : TPS7A16

NOTE: Qualified Version Definitions:

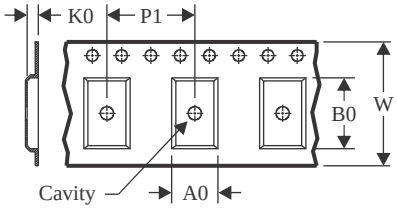
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

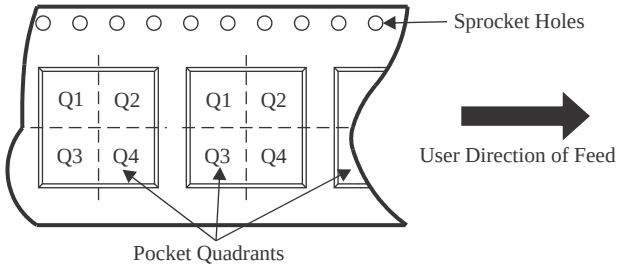


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

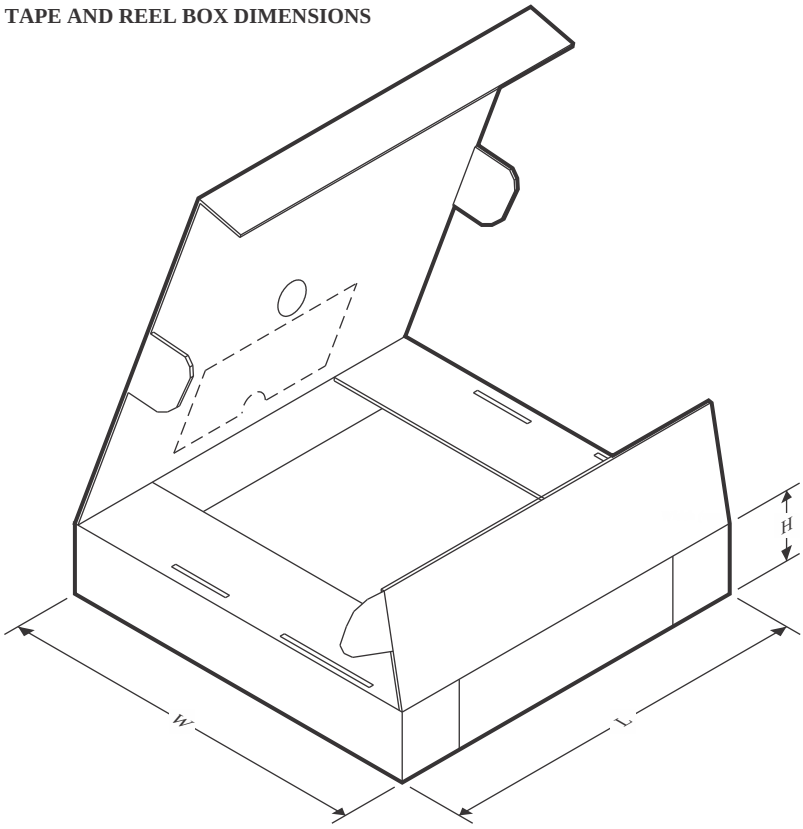
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A1601QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS7A1633QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS7A1650QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS7A1650QDGNRQ1	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A1601QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0
TPS7A1633QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0
TPS7A1650QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0
TPS7A1650QDGNRQ1	HVSSOP	DGN	8	2500	367.0	367.0	38.0

GENERIC PACKAGE VIEW

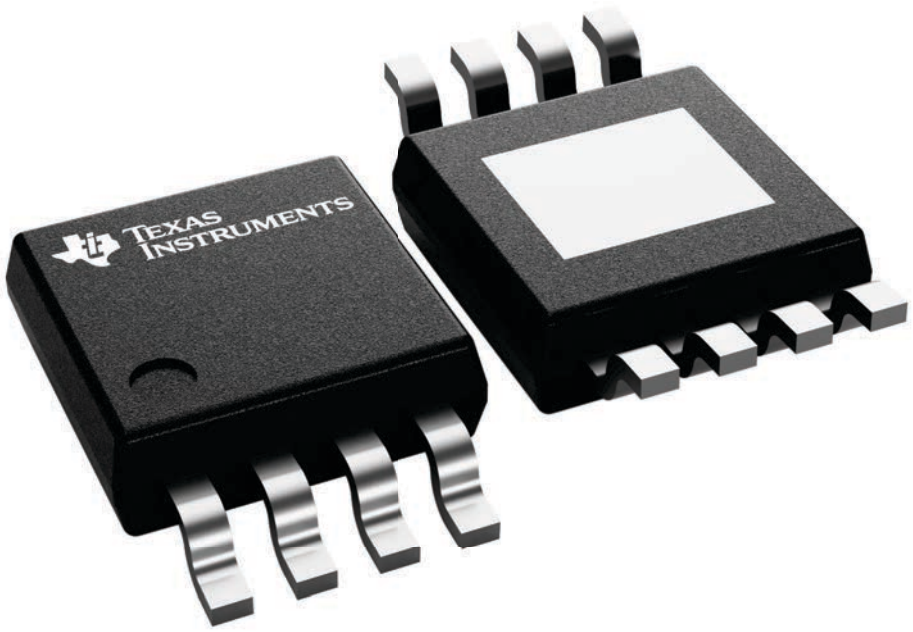
DGN 8

PowerPAD™ HVSSOP - 1.1 mm max height

3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

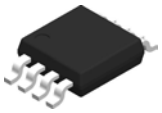
This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4225482/B

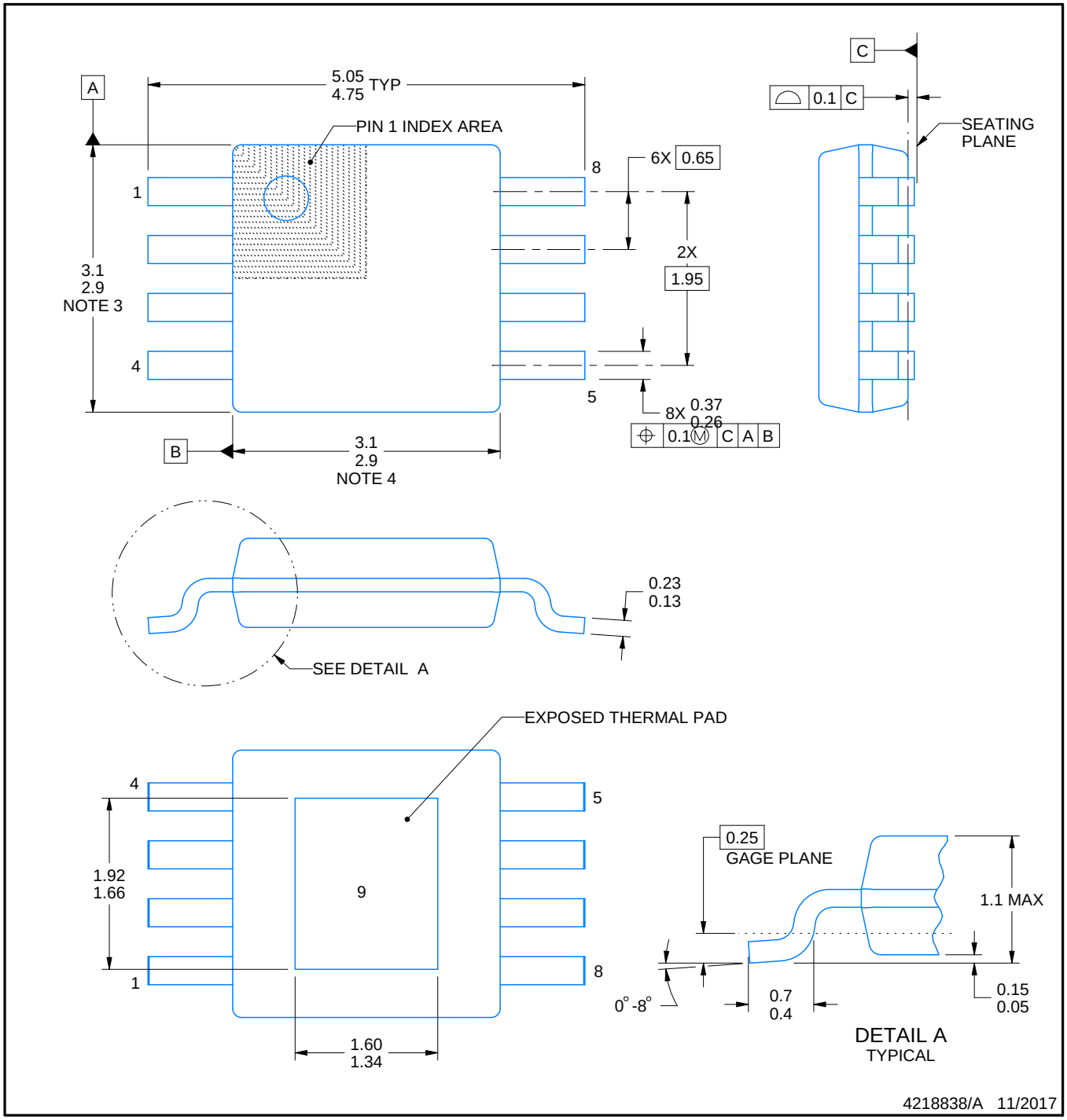
PACKAGE OUTLINE

DGN0008C



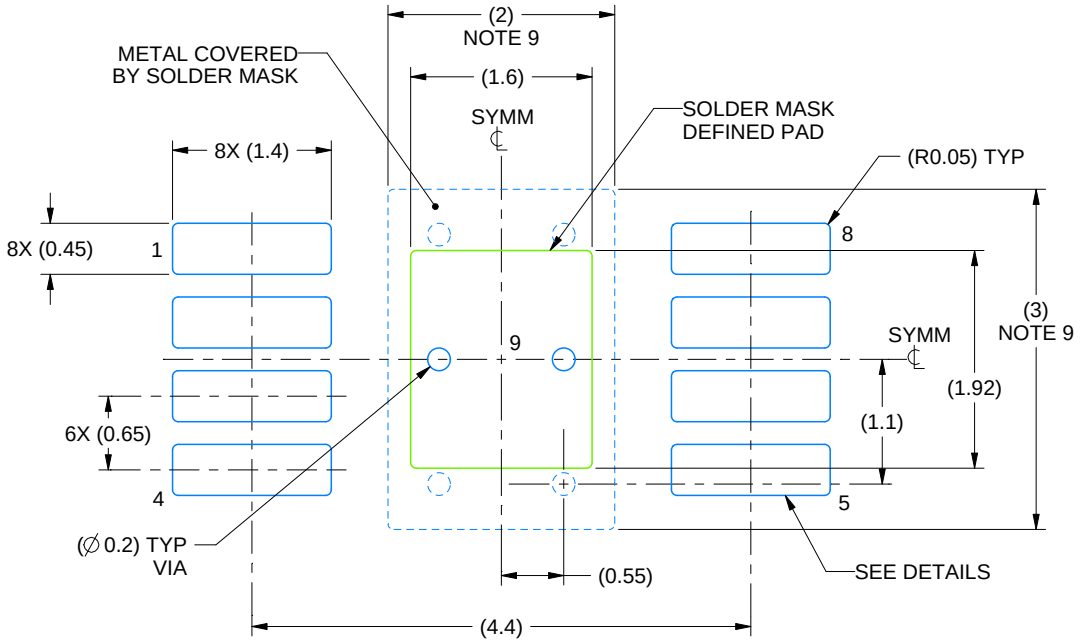
HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

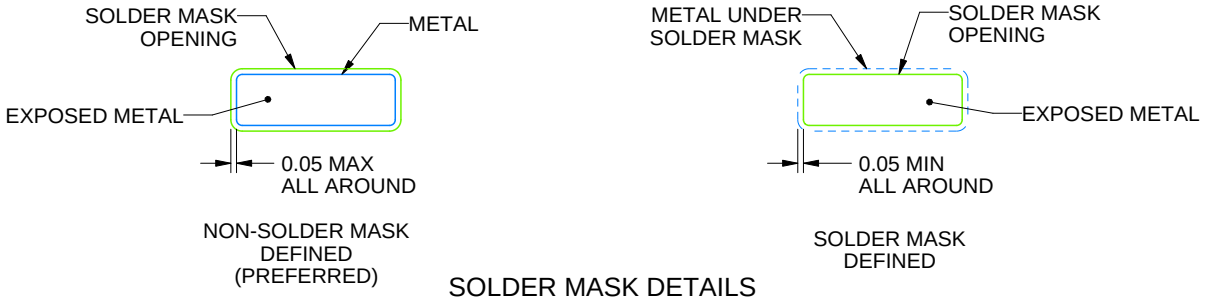


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

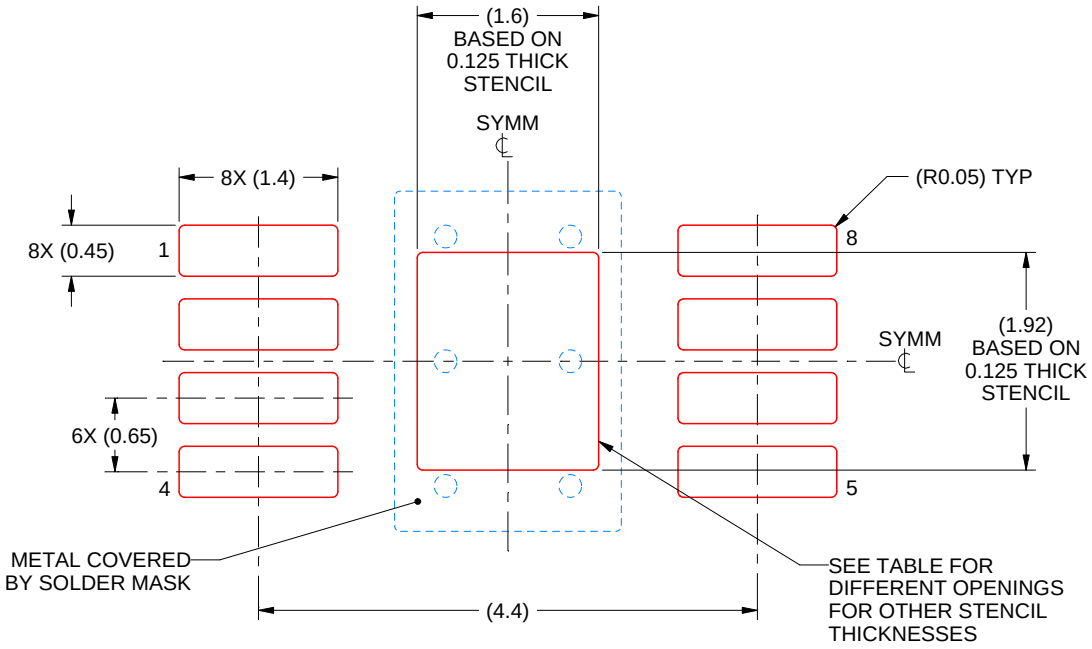


SOLDER MASK DETAILS

4218838/A 11/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.79 X 2.15
0.125	1.60 X 1.92 (SHOWN)
0.15	1.46 X 1.75
0.175	1.35 X 1.62

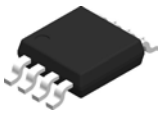
4218838/A 11/2017

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

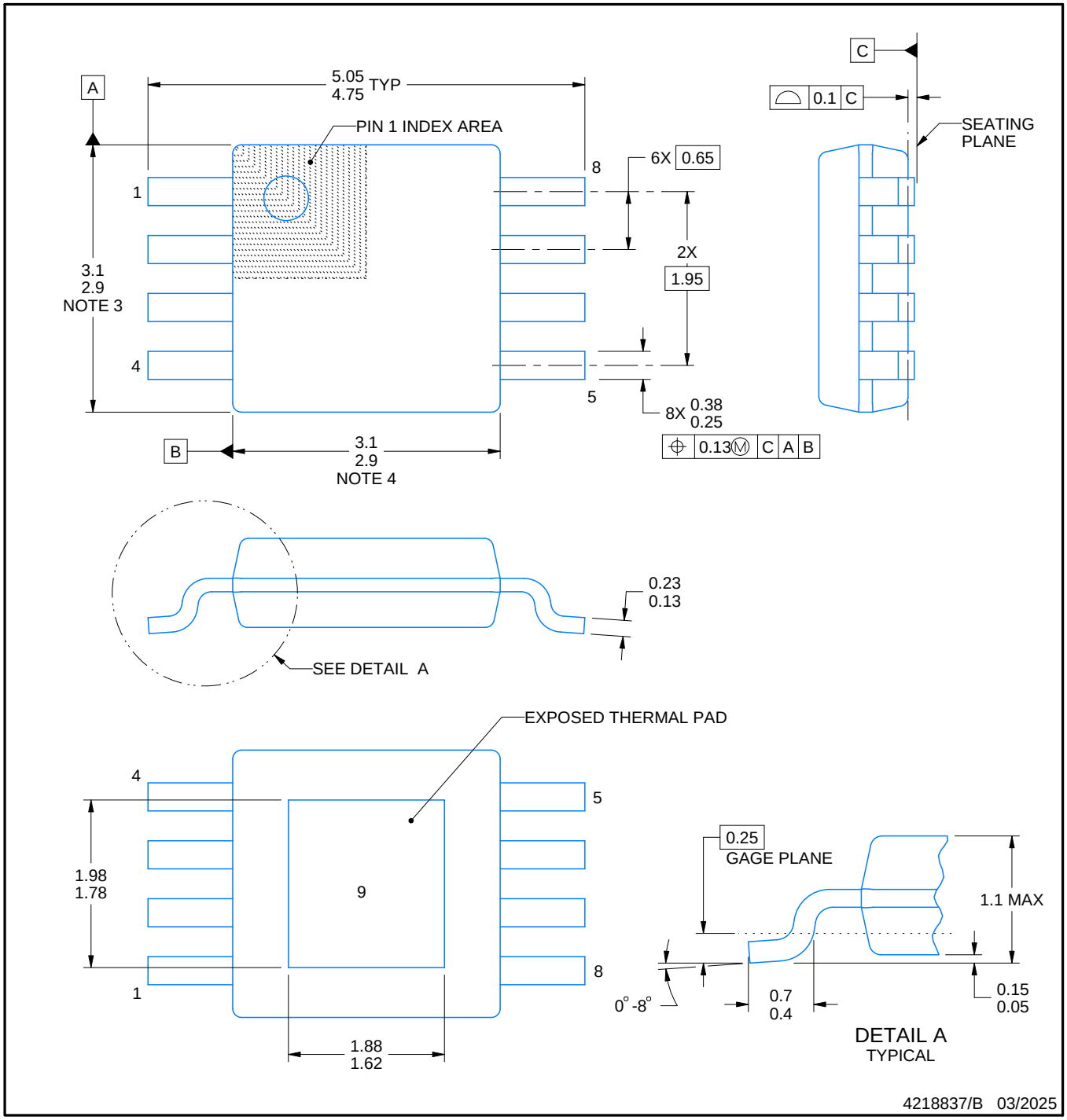
PACKAGE OUTLINE

DGN0008B



HVSSOP - 1.1 mm max height

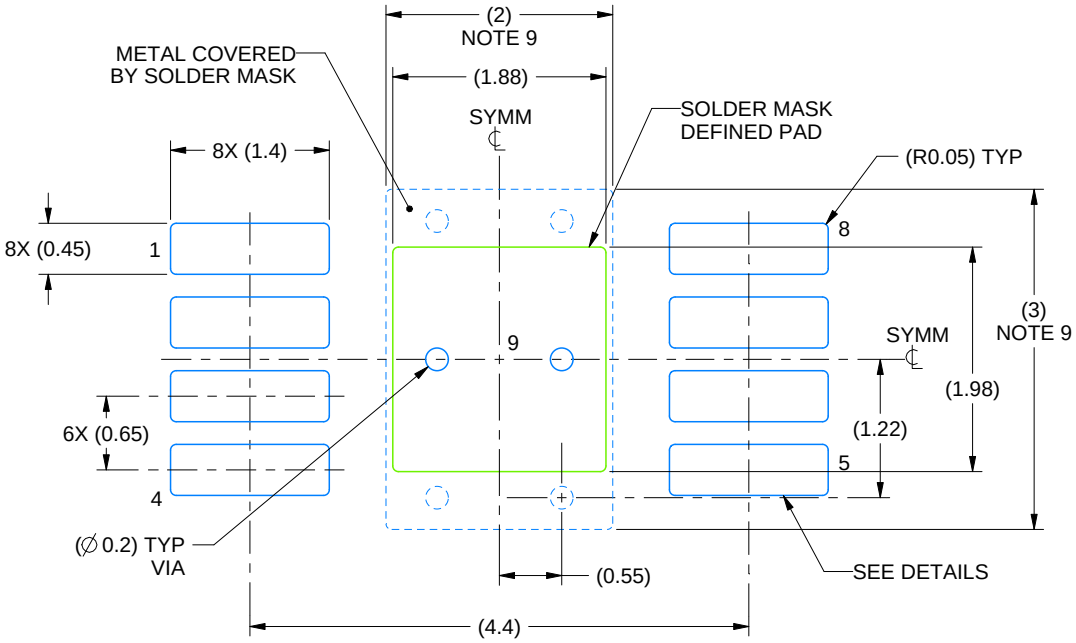
SMALL OUTLINE PACKAGE



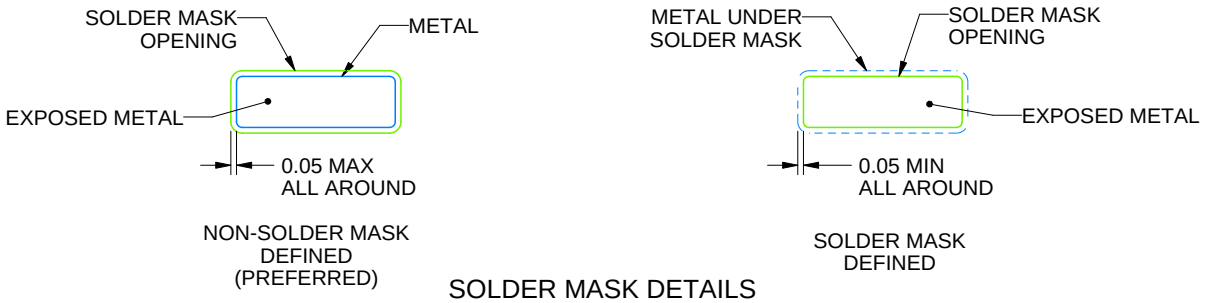
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

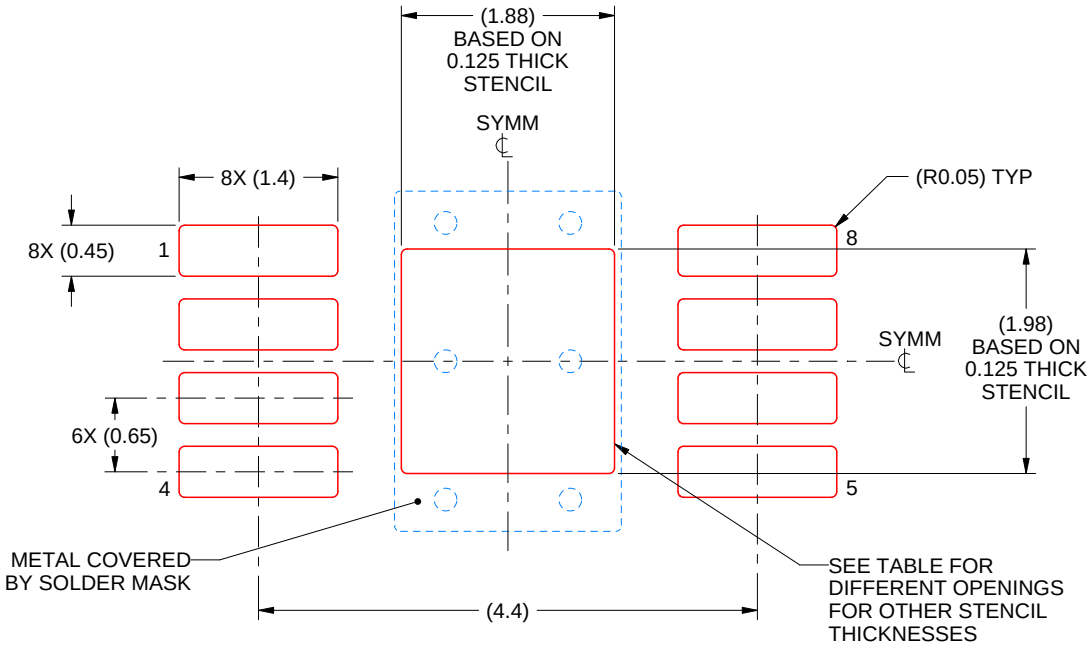


SOLDER MASK DETAILS

4218837/B 03/2025

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	2.10 X 2.21
0.125	1.88 X 1.98 (SHOWN)
0.15	1.72 X 1.81
0.175	1.59 X 1.67

4218837/B 03/2025

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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